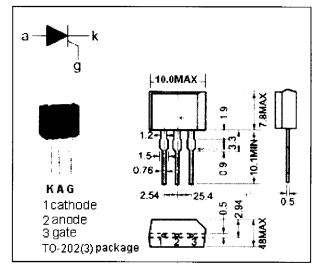
New Jersey Semi-Conductor Products, Inc.

20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A. Thyristors TELEPHONE: (973) 376-2922 (212) 227-6005 **X0402MF**

APPLICATIONS

- · Highly sensitive triggering levels
- For capacitive discharge ignitions, motor control in kitchen aids, overvoltage crowbar protection in low power supplies applications.



ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	MIN	UNIT	
	Repetitive peak off-state voltage	600	V	
V _{RRM}	Repetitive peak reverse voltage	600	V	
I _{T(AV)}	On-state current 180° conduction angle		A	
I _{TSM}	Non-repetitive surge peak on-state current t= 20ms	20	Α	
P _{G(AV)}	Average gate power dissipation $T_j = 125 ^{\circ}\mathbb{C}$	0.2	w	
Tj	Junction temperature	125		
T _{stg}	Storage temperature	-40 to + 150	°C	

ELECTRICAL CHARACTERISTICS (Tc=25°C unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	мах	UNIT
I _{RRM}	Repetitive peak reverse current	V _{RM} =V _{RRM} , R _{GK} =1k Ω V _{RM} =V _{RRM} , R _{GK} =1k Ω ,Tj=125°C		5 500	μA
I _{DRM}	Repetitive peak off-state current	V _{DM} =V _{DRM} , R _{GK} =1k Ω V _{DM} =V _{DRM} , R _{GK} =1k Ω , Tj=125°C		5 500	μA
\mathbf{V}_{TM}	On-state voltage	I _™ = 4A		1.7	V
I _{GT}	Gate-trigger current	V _{DM} =12V;R _L =140 Ω		200	μA
V _{GT}	Gate-trigger voltage	V _{DM} =12V;R _L =140 Ω		0.8	v
1 _H	Holding current	I _T = 0.05A		5	mA



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors